

Vishay Siliconix

P-Channel 40 V (D-S) MOSFET

DESCRIPTION

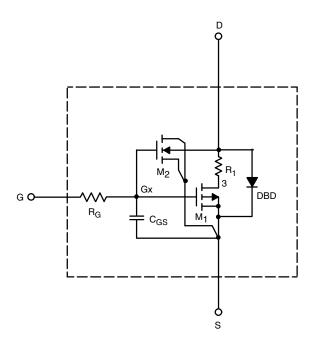
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55\,^{\circ}$ C to 125 $^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model Si7611DN

Vishay Siliconix

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	2	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -9.3 \text{ A}$	0.020	0.021	Ω
		V _{GS} = - 4.5 V, I _D = - 8.1 A	0.026	0.027	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 9.3 A	23	25	S
Diode Forward Voltage	V _{SD}	I _S = - 7.4 A	- 0.83	- 0.80	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 20 V, V _{GS} = 0 V, f = 1 MHz	2005	1980	pF
Output Capacitance	C _{oss}		224	215	
Reverse Transfer Capacitance	C _{rss}		163	175	
Total Gate Charge	Qg	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -9.3 \text{ A}$	39	41	nC
		V _{DS} = - 20 V, V _{GS} = - 4.5 V, I _D = - 9.3 A	21	21	
Gate-Source Charge	Q_{gs}		7	7	
Gate-Drain Charge	Q _{gd}		10	10	

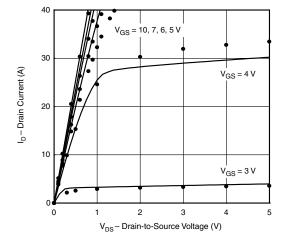
Notes

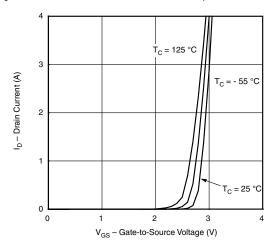
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

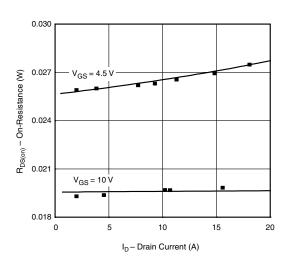
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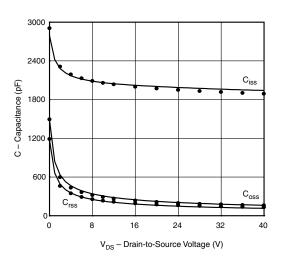
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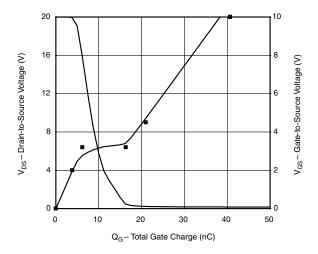
COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)

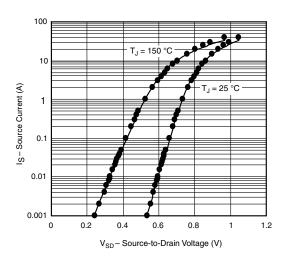












Note

· Dots and squares represent measured data.



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